

## 1<sup>st</sup>/2nd generation Laser-Produced Plasma source system for HVM EUV lithography

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## KOMATSU == EUVA



# Outline

**1. Introduction** 

### **2. Engineering Test source**

- 1<sup>st</sup> Generation (ETS) device: System experiment
  - Operation Data

### • 10Hz device: Critical issue experiment

- Vaporization experiment
- Ionization experiment
- Magnetic mitigation
- Pre-pulse and high CE

### 3. HVM EUV light source

- Product roadmap
- 2<sup>nd</sup> Generation device: Development status
  - Configuration
  - Latest status
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#### **EUV** sources キャピラリー 集光ミラー Plasma guiding Sn supply Magnet 真空容器。 High power パルス pulsed CO., laser 電源 -Plasma LPP: CO<sub>2</sub> laser and Sn source æ EUV 放電 ✓ High power pulsed CO₂ laser CO2 laser Magnetic field plasma mitigation $\checkmark$ 放電 ラズマ ✓ Pre-Pulse plasma technology 中間集光点:IF **EUV Collector** デブリシールド So-collector 真空ポンプ

Туре	LPP		DPP
Maker	Gigaphoton	Company A	Company B
Size	Large	Very Large	Small
Power (at present)	104W/21W	90W/20W	34W/34W
Plasma	No electrode	No electrode	Disc electrode
Mitigation	Pre pulse + Magnet	Gas	Gas+mechanical shutter
Life limitation	( several 1000 hr )	Several 10 hr	Several 10 hr
Bottle neck	-	Mirror	Electrode/Mirror
Remark	<ul> <li>Theoretically no limit</li> <li>Engineering works still to be done</li> </ul>	Trade off of power and lifetime	<ul> <li>Trade off of power and lifetime</li> <li>Trade off of power and beam quality</li> </ul>

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# **ETS system configuration**



## **System layout**





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## **System operation Data (ETS device)**

	SPIE 2010 (Feb.2010)	EUV Symposium (Oct.2010)	Latest Data (Feb,2011)
EUV power ( @ I/F)	69 W	104 W	42 W
EUV power ( clean @ I/F)	33 W	50 W	20 W
Duty cycle	20 %	20 %	<b>5%</b>
Max. non stop op. time	>1 hr	<1 hr	>7 hr
Average CE	2.3 %	2.5 %	<b>2.1%</b>
Dose stability :simulation	(+/- 0.15%)		-
Droplet diameter	<b>60</b> μ <b>m</b>	<b>60</b> μ <b>m</b>	<b>30</b> μm
CO <sub>2</sub> laser power	5.6 kW	7.9 kW	3.6kW



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## **Droplet generator lifetime improvement (\phi30 \mum)**

### > Operation time improved from <1 hour to >7 hours





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## **System operation result on ETS**

### >Long time system operation demonstrated

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 > Operation duration:
 > Droplet
 > Full repetition rate:
 > In burst clean power:
 20W (average) 25W (max)



## **Conclusion of ETS device experiment**

"ETS experiment clarified 3 key challenges are essential"

![](_page_9_Figure_2.jpeg)

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![](_page_10_Picture_0.jpeg)

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![](_page_10_Picture_17.jpeg)

![](_page_10_Picture_18.jpeg)

## **Collector mirror protect Concept**

### All Sn atoms should be ionized.

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- 1 Magnet field is effective for guiding ions not to going to mirror
- **②** All Sn fragments and atoms are needed to be ionized

![](_page_11_Figure_4.jpeg)

## **Critical issue investigation with 10Hz device**

- Double pulse optimization
- Debris mitigation mechanism
- Higher CE investigation

![](_page_12_Picture_4.jpeg)

![](_page_12_Picture_5.jpeg)

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![](_page_12_Picture_6.jpeg)

## **Setup configurations**

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![](_page_13_Figure_1.jpeg)

![](_page_13_Picture_2.jpeg)

## **Droplet transformation by pre-pulse**

#### Smaller fragments Spread homogeneously

![](_page_14_Picture_2.jpeg)

![](_page_14_Figure_3.jpeg)

![](_page_14_Picture_4.jpeg)

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## **Droplet shooting scheme**

#### **Proper pre-pulse condition**

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![](_page_15_Figure_2.jpeg)

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## Laser induced fluorescence (LIF) imaging for tin atom

Advantages

- Spectrally selective pumping and observation
- High sensitivity
- Cross sectional imaging with a sheet laser beam

![](_page_16_Figure_5.jpeg)

#### Grotrian diagram for tin atom

![](_page_16_Picture_7.jpeg)

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Principle of LIF

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## **Atom measurement by LIF - 2**

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# Remaining atoms was estimated by subtracting w/ CO2 vs w/o CO2 measurement

![](_page_17_Figure_2.jpeg)

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![](_page_18_Figure_0.jpeg)

## **Conclusion of 10Hz device experiment**

"Even with smaller than  $20\mu m$  droplet,

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### Ce=3.3% and perfect vaporization is simultaneously achieved"

![](_page_19_Figure_3.jpeg)

![](_page_20_Picture_0.jpeg)

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![](_page_20_Picture_17.jpeg)

![](_page_20_Picture_18.jpeg)

![](_page_21_Picture_0.jpeg)

## **EUV product roadmap**

![](_page_21_Figure_2.jpeg)

★ 1st source delivery > GL200E will be delivered to scanner manufacture at Mid Y2011.
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### **Clean power roadmap**

![](_page_22_Figure_1.jpeg)

EUV model		ETS	GL200E	GL200E+	GL400E
Drive laser power	kW	10	23	33	40
Conversion efficiency	%	3.0	5.0	5.0	6.0
C1 mirror collector angle	sr	5.5	5.5	5.5	5.5
efficiency*	%	74	74	74	74
C1 mirror reflectivity	%	(50)	57	57	57
Optical transmission	%	95	95	95	95
SPF (IR, DUV)	%	N/A**	62	62	62
Total EUV power (after SF	W	100	250	350	500

![](_page_22_Picture_3.jpeg)

\* Against hemisphere (Calculation base) \*\* w/o SPF

![](_page_22_Picture_5.jpeg)

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![](_page_23_Picture_0.jpeg)

## **GL200E proto constructed at Hiratsuka facility**

![](_page_23_Picture_2.jpeg)

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## **Main Amplifier performance**

> Main amplifier characteristics : experimental results

- ✓ ~10kW output achieved at 3kW input power
- ✓ Good beam quality: M<sup>2</sup><2.0

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![](_page_24_Figure_4.jpeg)

### Pointing stability of CO2 laser w/ control, duty cycle 30%

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![](_page_25_Figure_1.jpeg)

![](_page_25_Figure_2.jpeg)

### Beam profile

![](_page_25_Figure_4.jpeg)

Operation conditions	
Rep. rate [kHz]	100
Duty [%]	30
ON pls [pulse]	30,000
OFF time [msec]	700
Testing time [min]	120

![](_page_25_Picture_6.jpeg)

# **Pointing stability of Pre-Pulse laser**

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w/ control, duty cycle 30%

![](_page_26_Figure_2.jpeg)

![](_page_26_Figure_3.jpeg)

Beam profile

![](_page_26_Figure_5.jpeg)

Operation conditions	
Rep. rate [kHz]	100
Duty cycle [%]	30
ON pls [pulse]	30,000
OFF time [msec]	700
Testing time [min]	120

![](_page_26_Picture_7.jpeg)

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## **Droplet Generator for GL200E**

Video

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 $20 \,\mu$  m, 10kHz

![](_page_27_Picture_3.jpeg)

Slow image @nozzle

![](_page_27_Picture_5.jpeg)

## **Position stability at 10 kHz**

![](_page_28_Figure_1.jpeg)

ltem	unit	target	result
position stability x	um	+/-20	7
position stability z	um	+/-20	18

- > Position stability is within specification for proto.
- > Droplet generator on proto is working within spec.

![](_page_28_Picture_5.jpeg)

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![](_page_28_Picture_6.jpeg)

## Scalability toward to 250W clean power

- 3.3% CE realized by 20  $\mu\text{m}$  droplet

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- It indicates ~100W clean power if operated at 100kHz\*

![](_page_29_Figure_3.jpeg)

![](_page_30_Picture_0.jpeg)

KO

## **Research and development scenery**

![](_page_30_Picture_2.jpeg)

![](_page_30_Picture_3.jpeg)

![](_page_30_Picture_4.jpeg)

![](_page_30_Picture_5.jpeg)

![](_page_31_Picture_0.jpeg)

Presentation on 02 March @SPIE 2011 1

![](_page_31_Picture_2.jpeg)

## κομητίς

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We delayed 3 months. Now recovering !

### Real first EUV light ... High power and debris free light will come within a few weeks !

![](_page_31_Picture_7.jpeg)

![](_page_32_Picture_0.jpeg)

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![](_page_32_Picture_17.jpeg)

![](_page_33_Picture_0.jpeg)

# **Summary**

### 1<sup>st</sup> generation integrated setup LPP source (ETS) and 10 Hz device:

- One order smaller fragment (droplet size reduction from 60µm to 30 µm) extends operation time to 7 hours under 20W(clean power @I/F, 5%duty) level operation.
- 10Hz experiment proved debris mitigation concept experimentally. That is; proper pre-inonization and main ionization make >93% ionization. This technology enables clean light source with combination with magnetic field.
- 10Hz experiment clarify CE (Conversion Efficiency) improvement, with <20µm droplet we found the region where Ce >3.3% and perfect vaporization are simultaneously possible.

### 2<sup>st</sup> generation LPP source (GL200E):

- Concept of design and outline is reported.
- We already finished assembling and final engineering of components. The first light will be realized within a few weeks.

![](_page_33_Picture_9.jpeg)

![](_page_33_Picture_10.jpeg)

![](_page_34_Picture_0.jpeg)

# **Acknowledgments**

## Thanks to fund

This work was partly supported by the New Energy and Industrial Technology Development Organization NEDO Japan, and Komatsu Ltd.

![](_page_34_Picture_4.jpeg)

![](_page_34_Picture_5.jpeg)

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![](_page_35_Picture_0.jpeg)